BC~Series Transistors

Detailed product specifications are available on: us. 100y. com. tw

Part No.	Product No.	Manufacturer	Description	Marking	Pol	Ic(max)	Pc(max)	Vceo(max)	hfe(min.-max.)	Pins/Package
22486	BC807-40	WEITRON	PNP Silicon AF Transistors	5C	PNP	500mA	1A	-45V	250~600	3P/SOT-23
30164	BC807-40	PHILIPS	PHILIPS_PNP General Purpose Transistors	5C*	PNP	-0.5A	-250mW	-45V	250-600	3P/SOT-23
30116	BC817-25	PHILIPS	NPN Silicon AF Transistors(surface mount schottky barrier switching diode.)	6B	NPN	500mA	250mW	45V	160~400	3P/SOT23
22487	BC817-40	PHILIPS	NPN Epitaxial Silicon Transistor	6C	NPN	800mA	310mW	45V	250~630	3P/SOT-23
30118	BC846B	PHILIPS	NPN general purpose transistors	1B	NPN	100mA		65V	200-450	3P/SOT-23
25777	BC846B	WEITRON	NPN general purpose transistors	1B	NPN	100mA		65V	200-450	3P/SOT-23
41834	BC846BLT1	ON-Semi.	General Purpose Transistor		NPN	0.1A	225mW	65V	200~450	SOT-23
41836	BC846BLT1G	ON-Semi.	General Purpose Transistor		NPN	0.1A	0.225W	65V	200~450	SOT-23
22488	BC847B	WEITRON	NPN general purpose transistors	1F	NPN	100mA	250mW	45V	200-450	3P/SOT-23
30120	BC847B	PHILIPS	NPN general purpose transistors	1F	NPN	100mA	250mW	45V	200-450	3P/SOT-23
48405	BC847C	PHILIPS	NPN general purpose transistors		NPN	100mA		45V	420-800	3P/SOT-23
41837	BC847CLT1	ON-Semi.	General Purpose Transistor		NPN	0.1A	0.225W	45V	420~800	SOT-23
30132	BC848B	PHILIPS	General Purpose(NPN surface mount small signal transistor)	1K	NPN	0.1A	250mW	30V	200-450	3P/SOT-23
41838	BC848CLT1G	ON-Semi.	General Purpose Transistor		NPN	0.1A	0.225W	30V	420~800	SOT-23
41839	BC856BLT1G	ON-Semi.	General Purpose Transistor		PNP	0.1A	0.225W	65V	220~475	SOT-23
22491	BC857A	WEITRON	PNP SILICON PLANAR GENERAL PURPOSE TRANSISTORS	3E	PNP	-100mA	225mW	-45V	125-250	3P/SOT-23
41841	BC857ALT1G	ON-Semi.	General Purpose Transistor		PNP	0.1A	0.225	45V	125~250	SOT-23
22489	BC857B	PHILIPS	PNP General Purpose Transistor	3F*	PNP	-100mA	-250mW	-45V	220-475	3P/SOT-23
44981	BC857C	PHILIPS	PHILIPS 3P/SOT-23	3G*(-/t)	PNP	-100mA	-250mW	45v	420~800	3P/SOT-23
41843	BC858CLT1G	ON-Semi.	General Purpose Transistor		PNP	0.1A	0.225W	30V	420~800	SOT-23
44218	BCP56T1	ON-Semi.	ON_SOT-223_1000Tape and reel	BH	NPN	1A		100V		SOT-223/1000Tape and reel
37103	BCR8CM-12L	MITSUBISHI	MEDIUM POWER USE NON-INSULATED TYPE, PLANAR PASSIVATION TYPE			8A	5W	600V		TO-220
42447	BCX56	PHILIPS	NPN medium power transistor		NPN	1A		100v		SOT89
40920	BFR30	PHILIPS	N-channel field-effect transistors	m1p	N	10mA	250mW	25V		SOT-23
44972	BFR30LT1	ON-Semi.	N-channel field-effect transistors	m1p	N	10mA	250mW	25V		SOT-23

BD~Series Transistors

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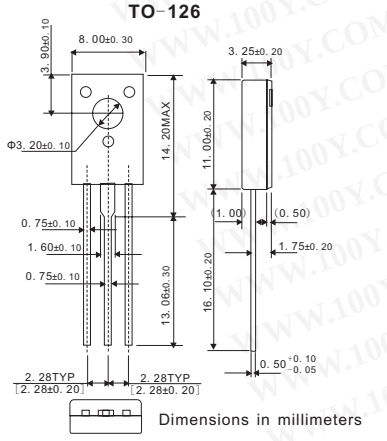
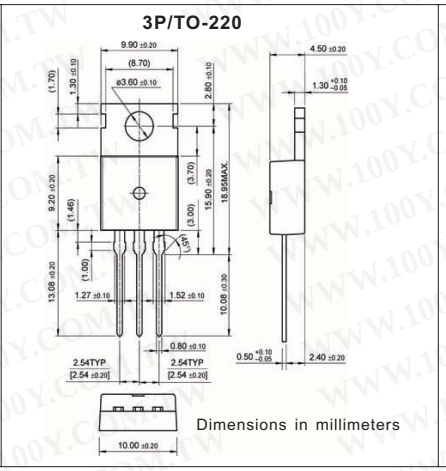
TO-126



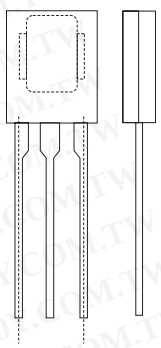
Dimensions in millimeters

3P/TO-220

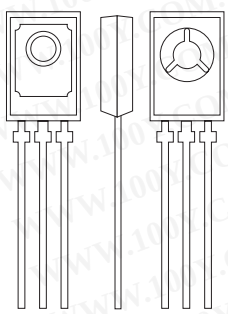


Dimensions in millimeters

TO-225AA



3P/SOT-32



Part No.	Product No.	Manufacturer	Description	Pol	Ic(max)	Pc(max)	Vceo(max)	hfe(min.-max.)	Pins/Package
27171	BD139-16	Fairchild	NPN Epitaxial Silicon Transistor	NPN	1.5A	12.5W	80V	40~160	3P/TO-126
22492	BD239C	PHILIPS	NPN Epitaxial Silicon Transistor	NPN	2A	30W	100V	15~40	3P/TO-220
14930	BD240BTU	ON-Semi.	Medium Power Linear and Switching Applications	PNP	-2A	30W	-80V	15-40	3P/TO-220
22496	BD240C	PHILIPS	PNP Epitaxial Silicon Transistor	PNP	-2A	30W	-100V	15~40	3P/TO-220
29069	BD676	MOTOROLA	Plastic Medium-Power Silicon PNP Darlingtons	NPN	4	40	45	750	TO-225AA
20130	BD681	ST(SGS)	COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS	NPN	4A	40W	100V		3P/SOT-32
14416	BD682	ON-Semi.	COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS	PNP					TO-225AA
19751	BD911	MOSPEC	COMPLEMENTARY SILICON PLASTIC POWER TRANSISTORS	NPN	15A	90W	100V	40-250	3P/TO-220
41213	BD911	ST(SGS)	COMPLEMENTARY SILICON POWER TRANSISTORS	NPN	15A	90W	100V	40-250	3P/TO-220
22497	BDX34A	MOSEL-VIT.	NPN Epitaxial Silicon Transistor	NPN	10A	70W	60V	750	3P/TO-220

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